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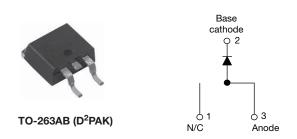


www.vishay.com

VS-MBRB1035PbF, VS-MBRB1045PbF

Vishay Semiconductors

High Performance Schottky Rectifier, 10 A



PRODUCT SUMMARY							
Package	TO-263AB (D ² PAK)						
I _{F(AV)}	10 A						
V _R	35 V, 45 V						
V_F at I_F	0.57 V						
I _{RM} max.	15 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Single die						
E _{AS}	8.0 mJ						

FEATURES

- 150 °C T_J operation
- TO-220 and D²PAK packages
- · Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 RoHS compliant HALOGEN
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201, class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	MBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	10	٨						
I _{FRM}	T _C = 135 °C	20	A						
V _{RRM}		35, 45	V						
I _{FSM}	t _p = 5 μs sine	1060	A						
V _F	10 A _{pk} , T _J = 125 °C	0.57	V						
TJ	Range	-65 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRB1035PbF	VS-MBRB1045PbF	UNITS					
Maximum DC reverse voltage	V _R	35	45	V					
Maximum working peak reverse voltage	V _{RWM}		45	v					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CON	IDITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	$T_{C} = 135 \text{ °C}, \text{ rated } V_{R}$		10					
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 kHz, T	_C = 135 °C	20					
Non-repetitive surge current	I _{FSM}	5 μs sine	Following any rated load condition and with rated V _{RRM} applied	1060	А				
		Surge applied at rated load conditi	150						
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 4 \text{ mH}$	8	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero ir Frequency limited by T _J maximum	2	А					

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS						
		20 A	T _J = 25 °C	0.84	V				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T _{.1} = 125 °C	0.57					
		20 A	1j = 125 C	0.72					
Maximum instantaneous reverse	I(1)	$T_J = 25 \ ^\circ C$	Rated DC voltage	0.1	mA				
current	I _{RM} (1)	T _J = 125 °C	haled DC vollage	15					
Threshold voltage	V _{F(TO)}			0.354	V				
Forward slope resistance	r _t	ij = ij maximum	$T_J = T_J maximum$		mΩ				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal rang	600	pF					
Typical series inductance	Ls	Measured from top of term	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction tempera	ture range	TJ		-65 to +150	°C			
Maximum storage temperat	ure range	T _{Stg}		-65 to +175	-0			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torgue	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking device			Case style D ² PAK	MBRE	31035			
			Case signe D-FAIX	MBRE	31045			

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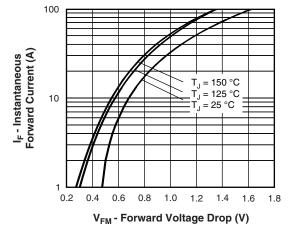


Fig. 1 - Maximum Forward Voltage Drop Characteristics

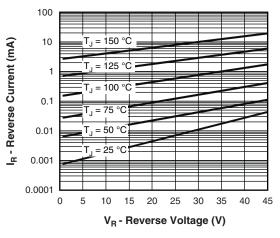


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

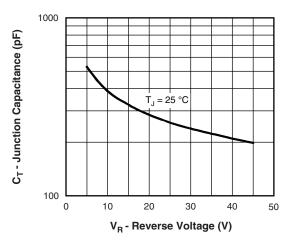


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

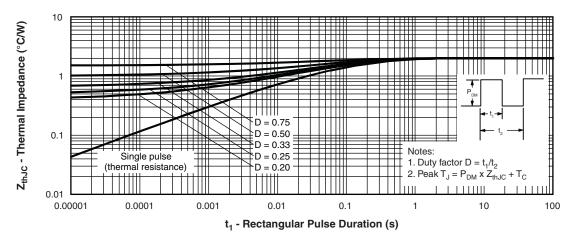


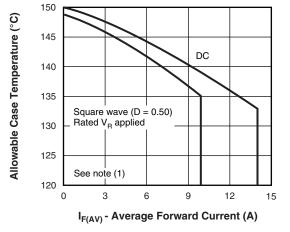
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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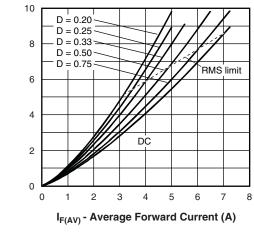
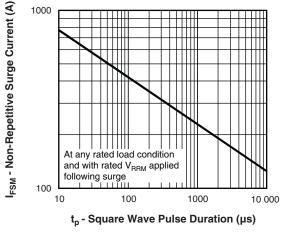


Fig. 6 - Forward Power Loss Characteristics



Average Power Loss (W)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R



VS-MBRB1035PbF, VS-MBRB1045PbF

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ORDERING INFORMATION TABLE

Device code	VS-	MBR	В	10	45	TRL	PbF	
		2	3	4	5	6	7	
	 Vishay Semiconductors product Essential part number B = surface mount Current rating (10 = 10 A) Voltage ratings S - Voltage ratings 35 = 35 V 45 = 45 V 							
	• TRL = tape and reel (left oriented)							
	 TRR = tape and reel (right oriented) PbF = lead (Pb)-free 							

LINKS TO RELATED DOCUMENTS								
Dimensions <u>www.vishay.com/doc?95046</u>								
Part marking information	www.vishay.com/doc?95054							
Packaging information	www.vishay.com/doc?95032							
SPICE model	www.vishay.com/doc?95293							

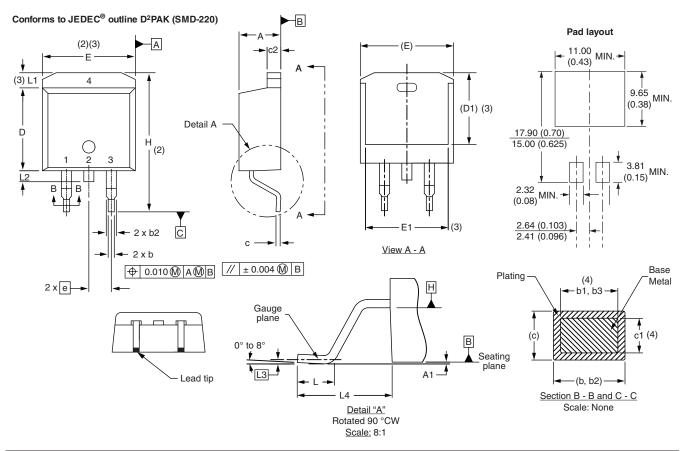
Outline Dimensions



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INCHES		NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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